



Beyond Niobium SRF materials:

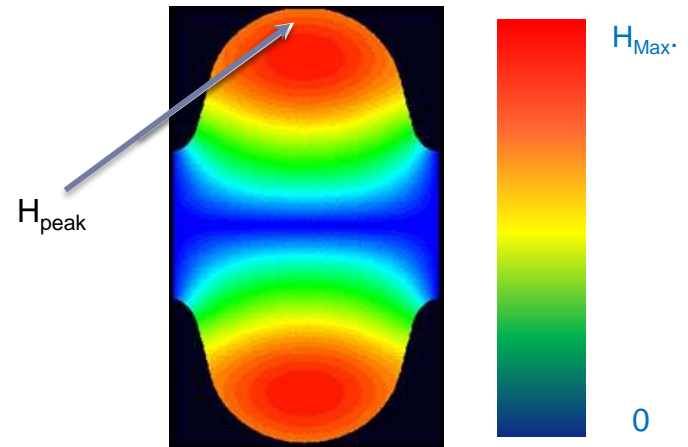
Thin films and new
multilayer superconductors

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- Superconductivity only needed inside :
 - Thickness $\sim < 1 \mu\text{m} \Rightarrow$ thin films
 - » (onto a thermally conductive, mechanically resistant material, e.g. Cu)
- Issues : getting “defect free” superconductor
- $Q_0 \propto 1/R_s \propto T_c$
- $E_{\text{acc}} \propto H_{\text{RF}}$
- Limit = transition of the SC material @ H_{peak}
 - Which transition should we consider!???



B field mapping in an elliptical cavity

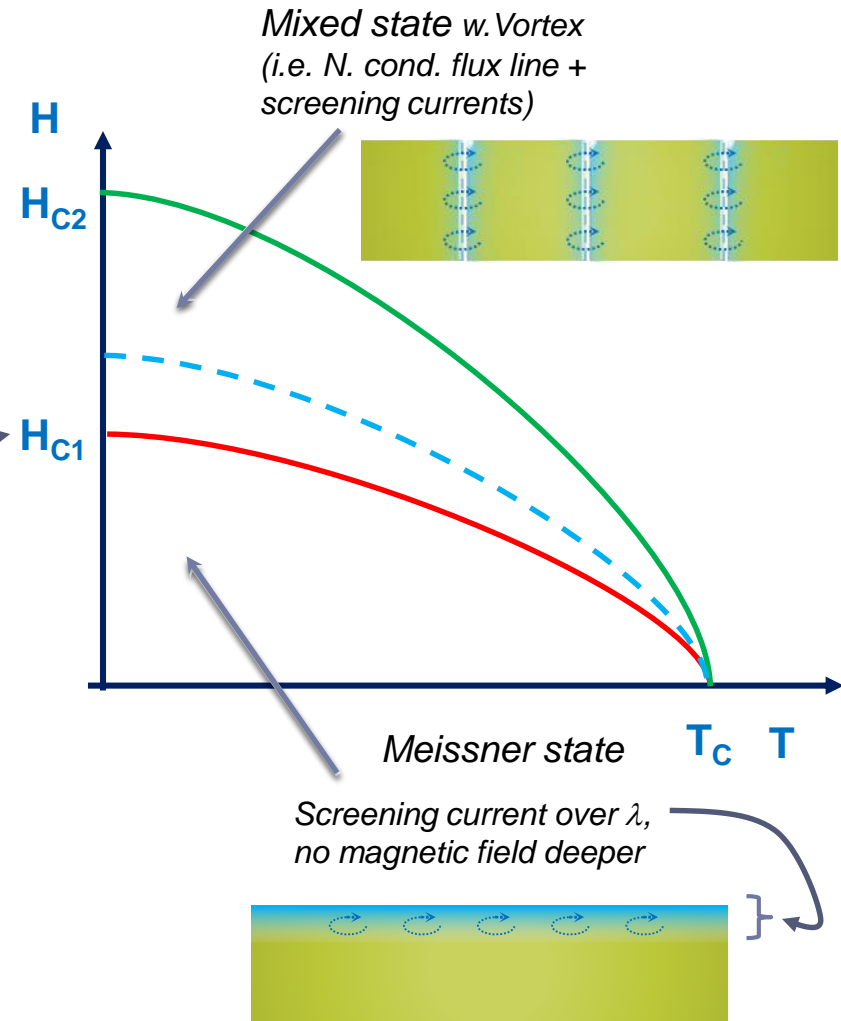
- SC phase diagram

- All SC applications **except SRF:** mixed state w. vortex
 - » Vortices dissipate in RF !
- SRF => Meissner state **mandatory !**
- H_{C1} = limit Meissner/mixed state
- Nb highest H_{C1} (180 mT)
- « Superheating field » (?) :



Metastable state favorized by H// to surface

- » Difficult to get in real life !



- Ideal case

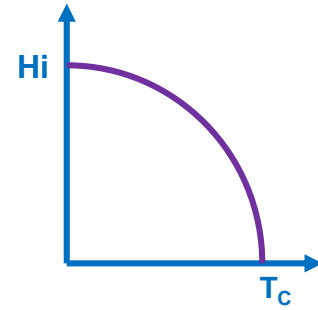
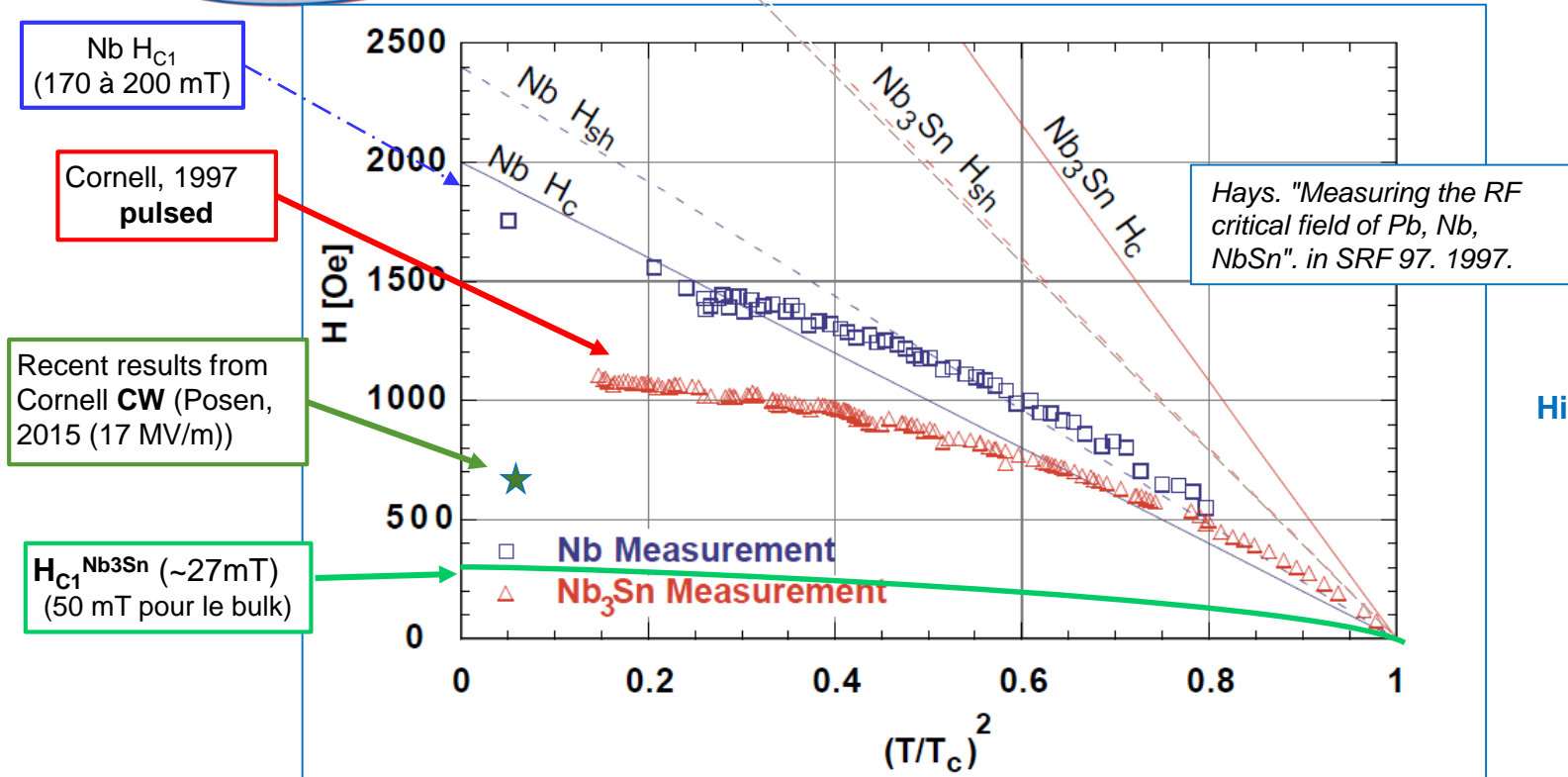
- Field // surface, => surface barrier (boundary conditions)
- Field // surface start to enter SC @ $H_{SH} > H_{C1}$
- @ $H \geq H_{SH}$ Vortex oscillate in RF \rightarrow dissipations
- Most favorable SC : Nb_3Sn , MgB_2 (high T_C , high H_{SH})



$H_{SH}^{Nb_3Sn}$
(~ 400 mT @ 0 K)

EuCARD²

Nb₃Sn: reaching H_{SH} ?



$$H_i = H_i^0 \left[1 - \left(\frac{T}{T_c} \right)^2 \right]$$

Dissipations :

$$\frac{1}{2} \int \int R_s H^2 dS$$

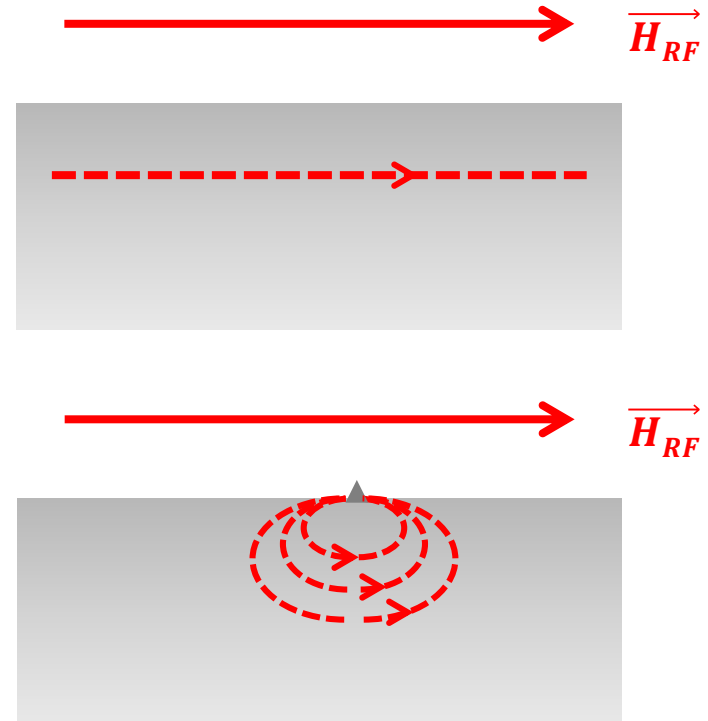
- **Vortices enter more easily at low temperature**
 - @ T~TC : H low=> low dissipations => easy thermal stabilisation
 - @T<<TC : H high=> even small defects => vortex penetration and high dissipation
- **Reduce defect density (but which ones !?)**

- Ideal case

- Field // surface, => surface barrier (Bean Livingston)
- Vortex // surface start to enter @ $H_{SH} > H_{C1}$
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- Real life: defects at surface

- Early vortex penetration (bundle) @ H_{C1} (or less !)
- Formation of current loops
- Avalanche
- Oscillations in RF => dissipations
- What kind of defects do we fear ???

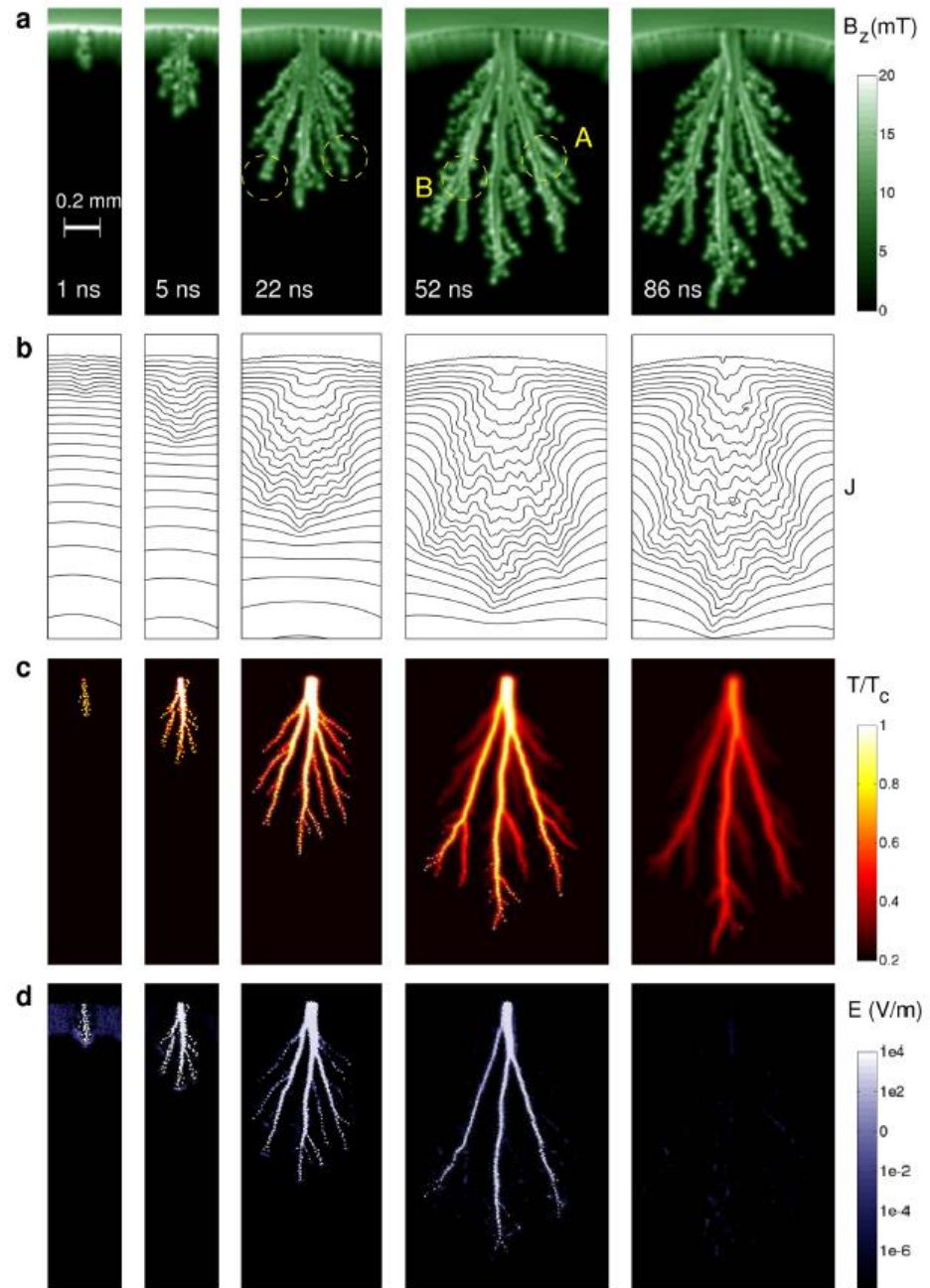


Vortices: Avalanche penetration

- $\sim 100 \mu\text{m}$ in 1 ns (\sim RF period)=
- Compare with λ (field penetration depth)
 - Nb : $\sim 40 \text{ nm}$
 - $\text{MgB}_2 \sim 200 \text{ nm}$

MgB₂ example

http://www.nature.com/srep/2012/121126/srep00886/full/srep00886.html?message-global=remove&WT.ec_id=SREP-20121127



- **Ideal case**

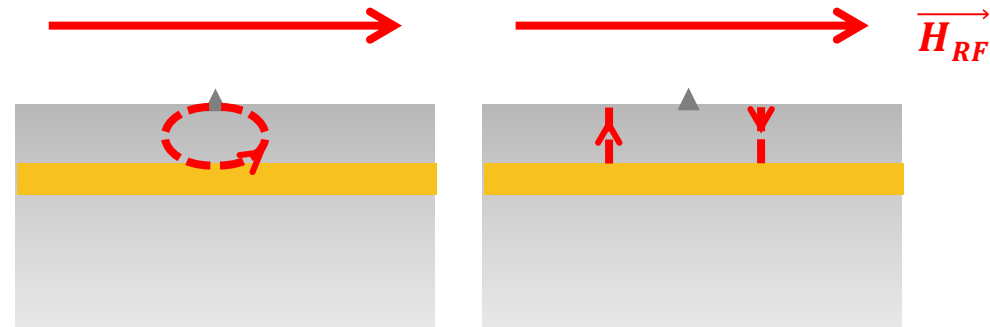
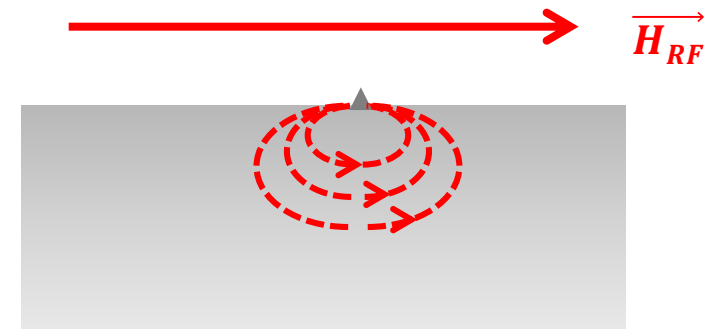
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- **Defect at surface**

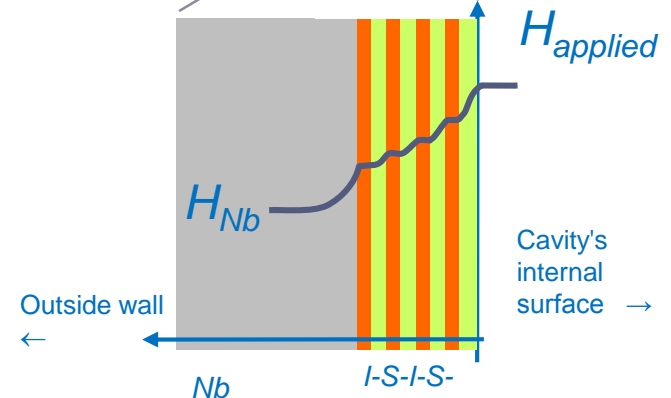
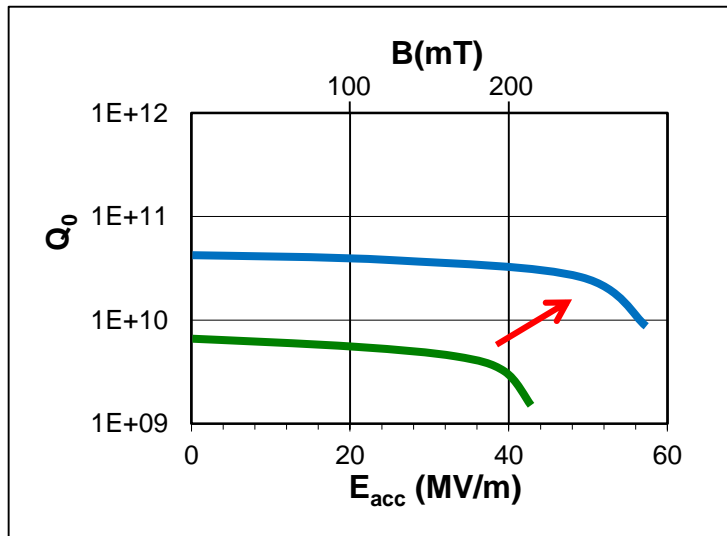
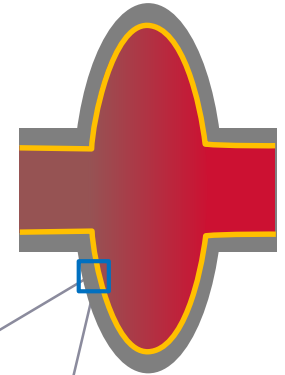
- Early vortex penetration (bundle) @ H_{C1} (or less ?)
- Formation of current loops
- Avalanche
- Oscillations in RF => dissipations
- What kind of defects do we fear ???

- **Dielectric layer**

- Small \perp vortex (short \rightarrow low dissipation)
- Quickly coalesce (w. RF)
- Blocks avalanche penetration
- => Multilayer concept for RF application
- Most favorable SC : Nb_3Sn , MgB_2 , NbN ...



- Surface screening and low R_s
 - Thin SC films. $d < \lambda \Rightarrow$ Artificial enhancement of H_{C1}^*
 - » Thin layers stand high fields without vortex nucleation
 - » Partial screening of $H_{applied}$
 - Niobium surface screening: allows higher field in the cavity
 - $T_C^{NbN} \gg T_C^{Nb} \Rightarrow R_S^{NbN} \ll R_S^{Nb} \Rightarrow Q_0^{multi} \gg Q_0^{Nb}$



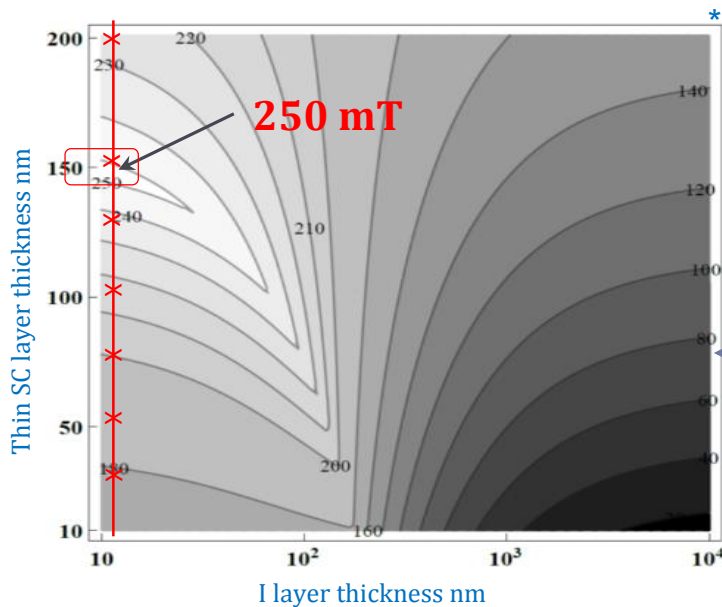
$$H_{Nb} = H_{appl} e^{-\frac{Nd}{\lambda}} \quad **$$

* In theory 20 nm NbN : $H_{C1} \times \sim 200$

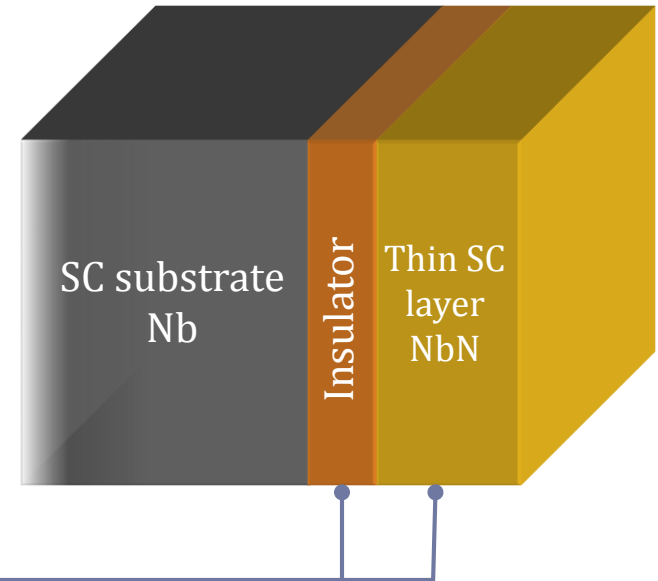
** Simplified model from Gurevich

- Optimization of ML structure
 - Series of NbN single layer/MgO/Nb samples
 - » Deposited by reactive magnetron sputtering on silicon substrate (collaboration Grenoble INP and CEA INAC)
 - » NbN chosen because well mastered /SC electronics
 - Comparison w. recent theoretical developments
- Development of specific sample measurement tools
 - Properties of thin films in SRF operation conditions cannot be done w. conventional techniques

- Advanced model: \exists only for single layer; includes:
 - Boundary conditions
 - Role of Nb sublayer



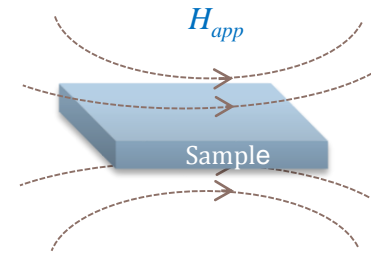
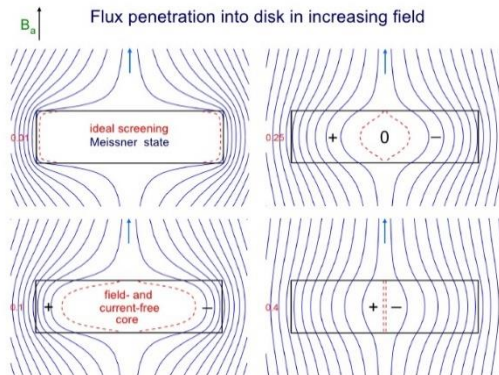
H_{max} optimum ~ 250 mT which is higher than of thick Nb (170 mT)



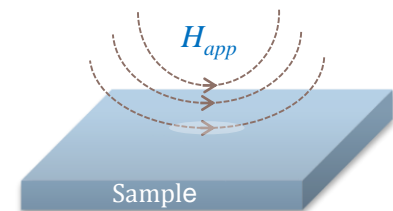
- Prediction for NbN ($T_C \sim 15$ K, $\lambda = 200$ nm)
 - T. Kubo (2014)³ ~ 140 nm
 - A. Gurevich (2015)⁴ ~ 160 nm
- WP 12.2 (subtask 2) experimentals:
 - NbN not most favorable on paper...
 - but “easy” to make (cf SC electronics)

²C.Z. Antoine, et al. *APL* 102, 102603 (2013). ³T. Kubo et al, *Appl. Phys. Lett.* 104, 032603 (2014). ⁴A. Gurevich, *AIP Advances* 5, 017112 (2015).

- Develop new SCs multilayers at higher fields => Need for specific characterization tools
- Conventional Magnetometer (SQUID) gives ambiguous results:
 - Uniform field around the sample
 - Demagnetization (orientation, edge, shape) effects
 - Exact local field configuration not known



SQUID magnetometer principle

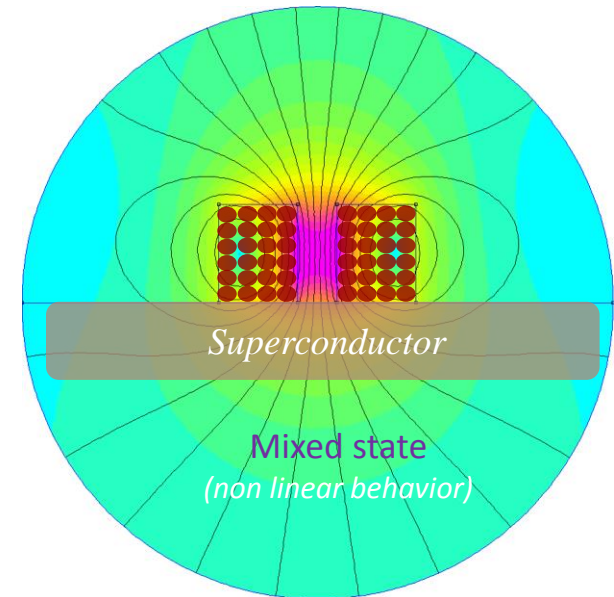
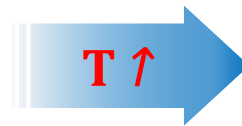
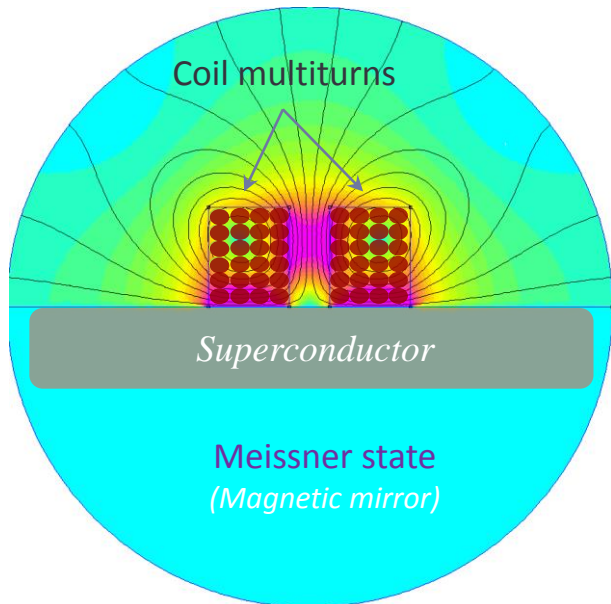


Local magnetometer principle



EuCARD² 3rd harmonic measurement of H_{C1} / H_{SH}

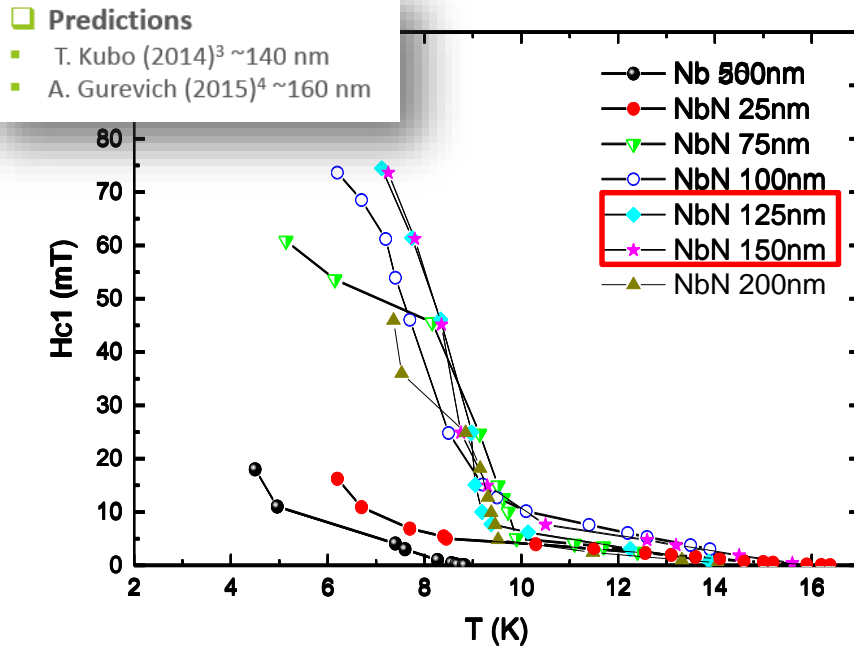
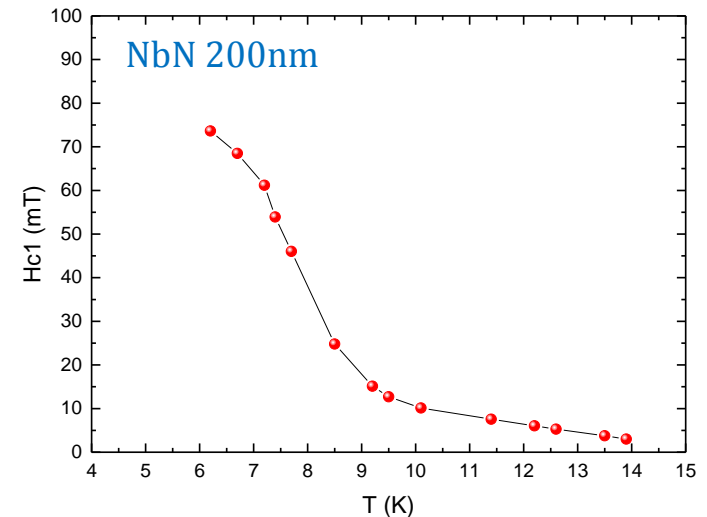
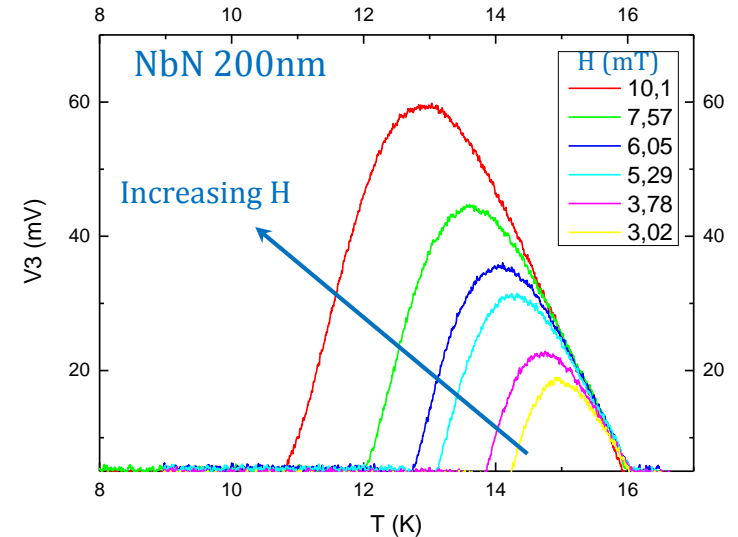
- Building a setup ~operating conditions for SRF (2K-20K; $H \gg 150$ mT)
 - (tbc existing facilities⁶ : $> 4,5$ K or 70 K and $B_{max} \sim 15-20$ mT)
 - Magnet size \ll sample size (infinite plane approx.)
 - Field decreases quickly away from the coil
 - Measurement of H_{C1} on sample without edge/demagnetization effect
 - Exploring new SCs /multilayers at accelerator operating condition



⁵ J. H. Claassen, et al. *Rev. Sci. Instrum.*, Vol. 62, 4 (1991).

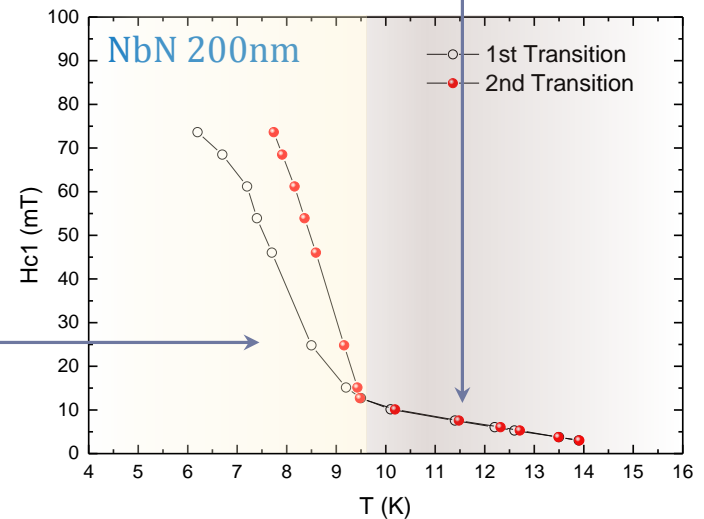
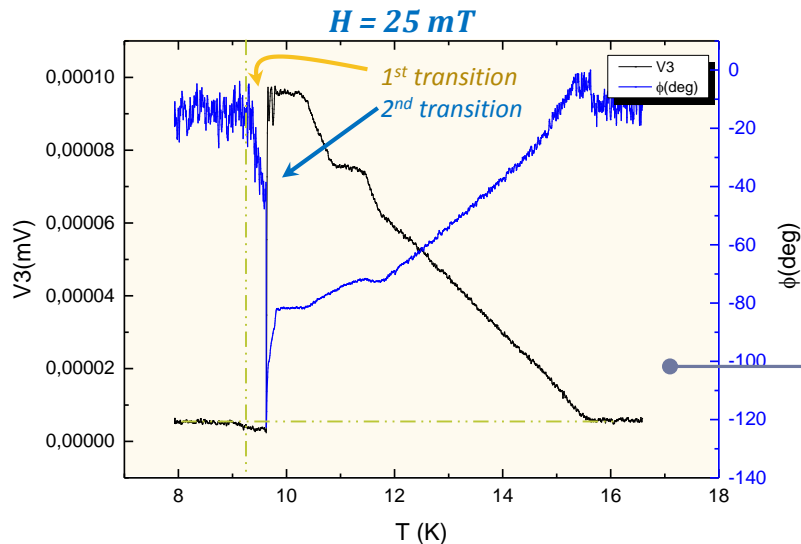
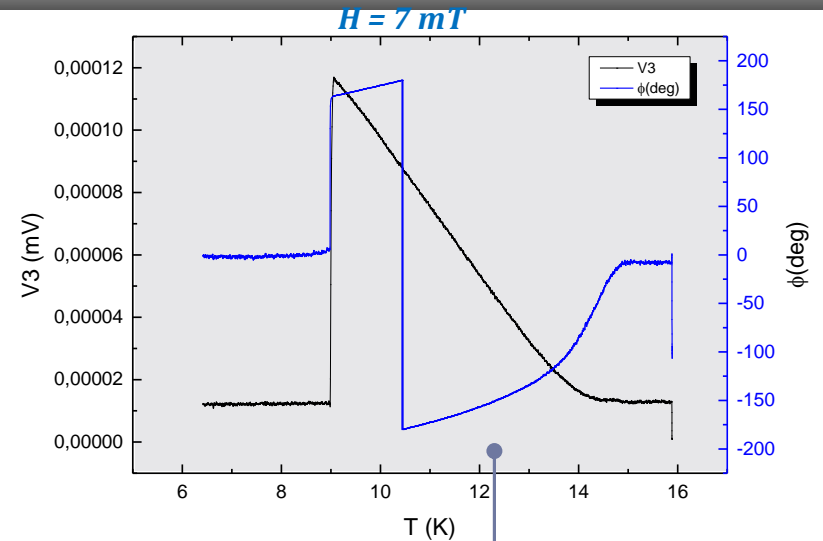
⁶ M. Aurino, et al., *Journal of Applied Physics*, 98, 123901 (2005).

- Series of NbN single layer/MgO/Nb
 - Deposited by reactive magnetron sputtering on silicon substrate (collaboration Grenoble INP and CEA INAC)
 - Insulator = MgO
 - Thick Nb layer to mimic bulk Nb

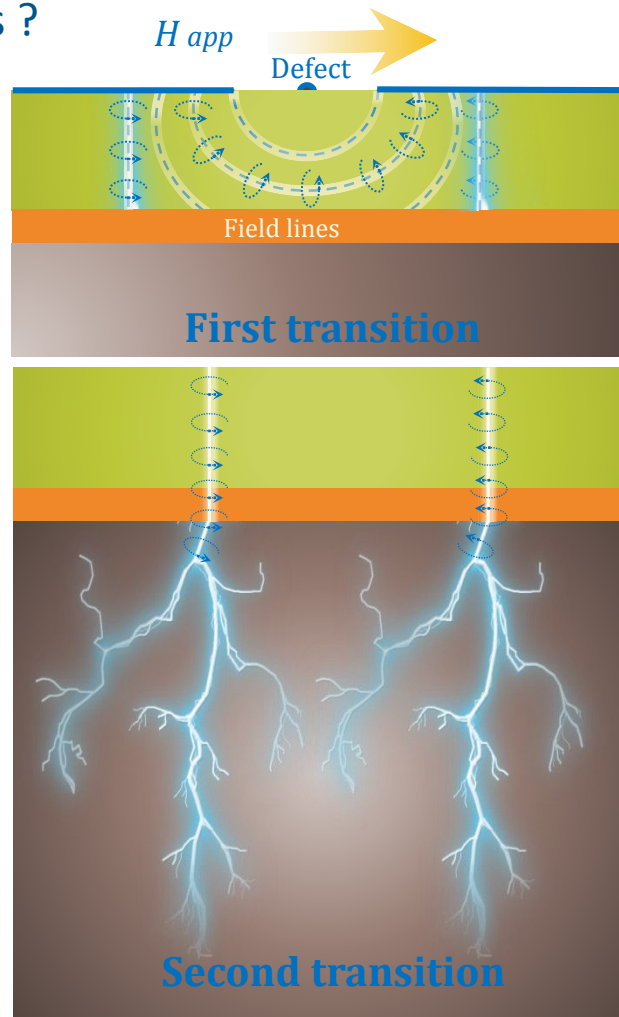
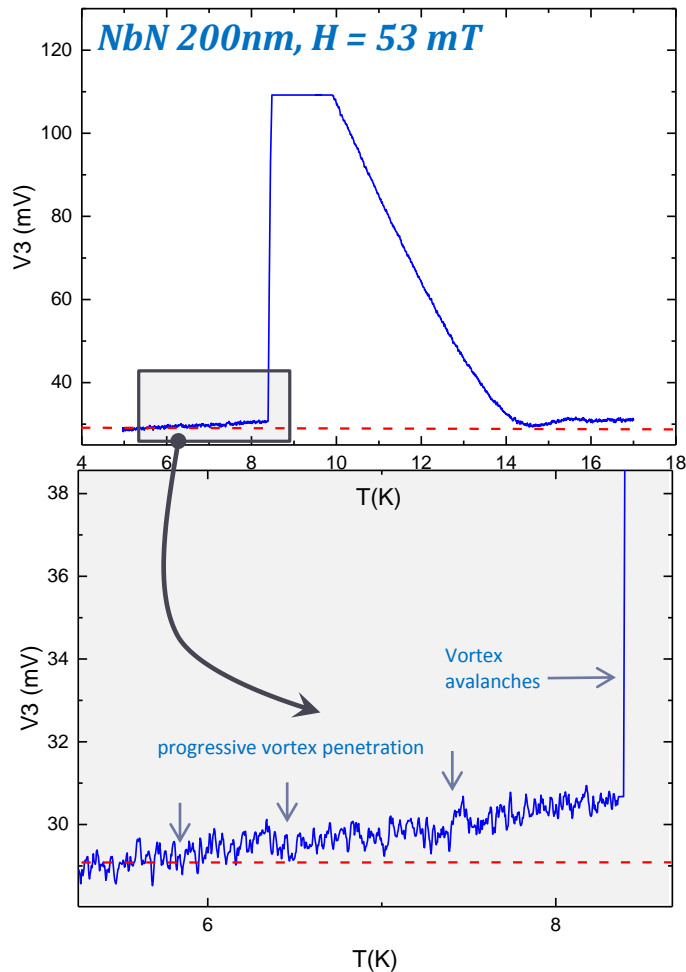


What do we measure ?

- Determination of H_{c1}
 - Low field => one transition
 - High field => two transitions
 - » 1st transition with low dissipation
 - » 2nd transition very strong dissipation
- Why do we have two transitions ?



- Why do we have two transitions ?



- Thin SC layer NbN
- Insulator MgO
- Thick SC layer Nb

- $H //$ surface \Rightarrow surface barrier⁷
- A defect locally weakens the surface barrier
- 1st transition, vortex blocked by the insulator ~ 100 nm \Rightarrow low dissipation.
- 2nd transition, propagation of vortex avalanches (~ 100 μ m) \Rightarrow high dissipation.
- Dielectric layer = efficient protection !!!**

- **Scientifically:**
 - Very challenging upstream, discovery, R&D
 - Efficiency of multilayer concept demonstrated
 - » Field enhancement => higher SRF performances
 - » Results close from theory => will help optimization
 - Protection against “avalanches” => can accommodate defective (realistic) material
- **Future :**
 - EUCARD3 (ARIES) covers only a little of the work to be done
 - Other funding sources needs to be found
- **Practically:**
 - Many difficulties to (propose and) follow a realistic schedule within EUCARD framework
 - The foreseen program and the collaborations started will be pursued beyond the end of EUCARD2

Thank you for your attention



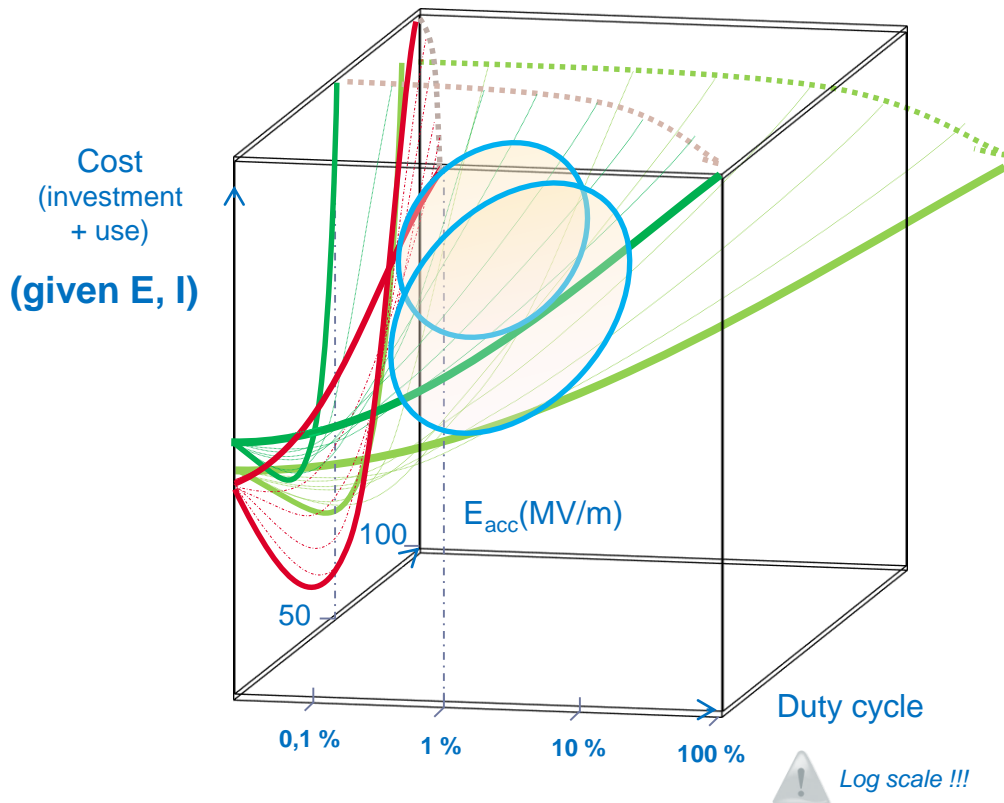
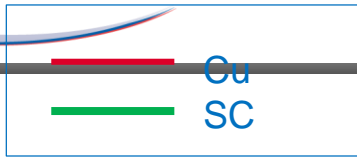
Claire
ANTOINE



Muhammad
ABURAS

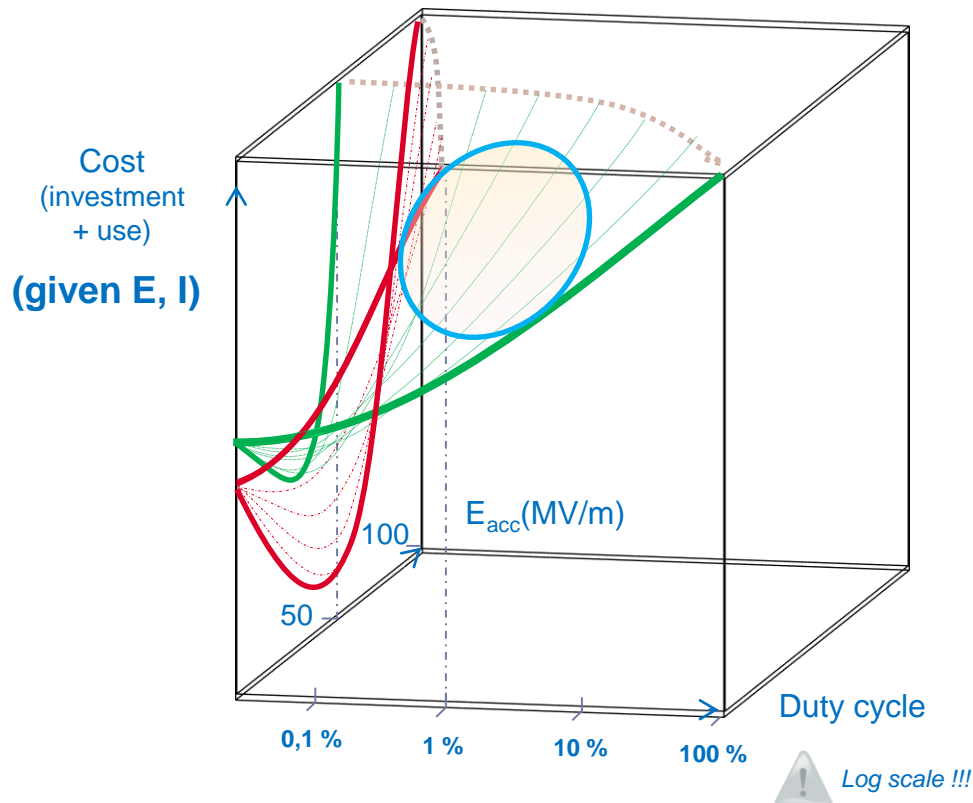


Aurelien
FOUR



Costs elements

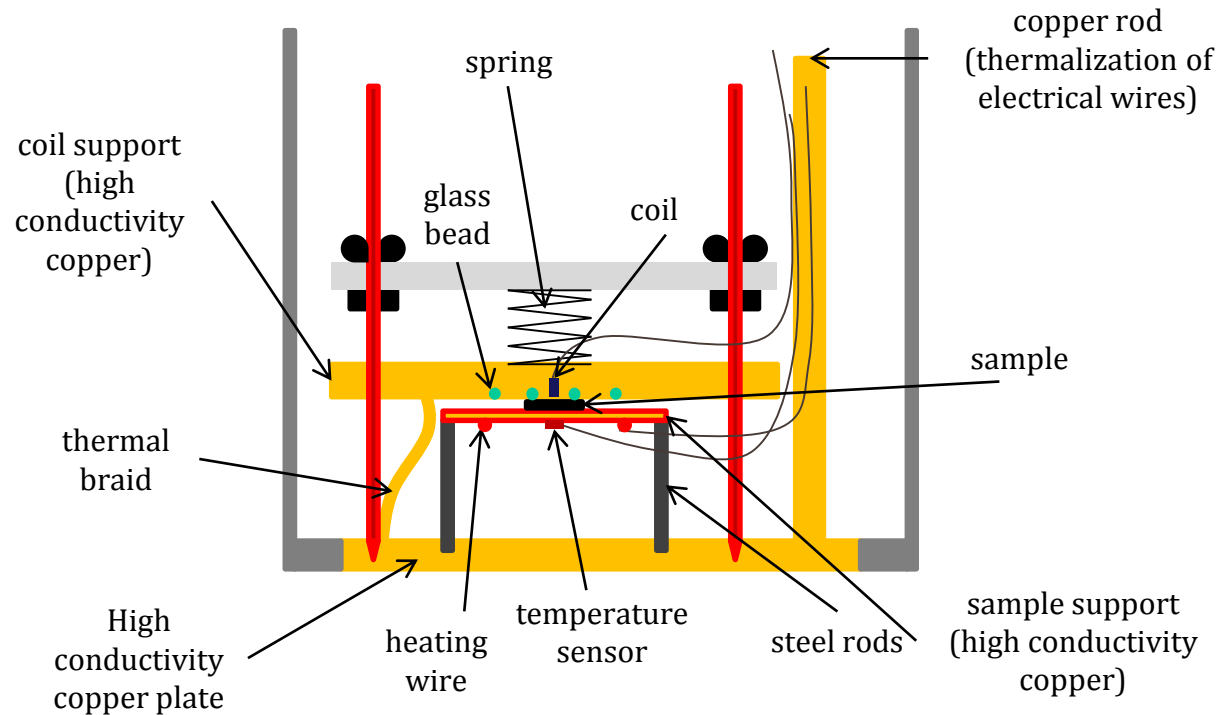
- coûts ↑ avec C.U.
- ∃ Optimum E_{acc}
 - » Low E_{acc} => longer accelerator => fab. costs ↑
 - » High E_{acc} => RF cost ↑ for Cu & cryogenics ↑ for SC
- Other example: CLIC vs ILC (e+/e- collider)
 - » ILC : C.U. = 0,5 % @ 1,3 GHz
 - » CLIC : C.U. = 0,001 % @ 12 GHz
- Linac costs
 - » ~ 1/3 tunnel, building
 - » ~ 1/3 niobium, cryo
 - » ~ 1/3 RF, beam control



elements de coûts

- coûts ↑ avec C.U.
- ∃ champ accel. Optimum
 - » Faible champ => accélérateur + long => coûts ↑
 - » Fort champ => coûts RF ↑ pour cuivre et coûts cryogéniques ↑ pour supra
- Autre exemple : CLIC vs ILC (collisionneurs e+/e- usines à Higgs)
 - » ILC : C.U. = 0,5 % @ 1,3 GHz
 - » CLIC : C.U. = 0,001 % @ 12 GHz
- Coûts linac
 - » ~ 1/3 tunnel, BTP
 - » ~ 1/3 niobium, cryo
 - » ~ 1/3 RF, contrôles faisceau

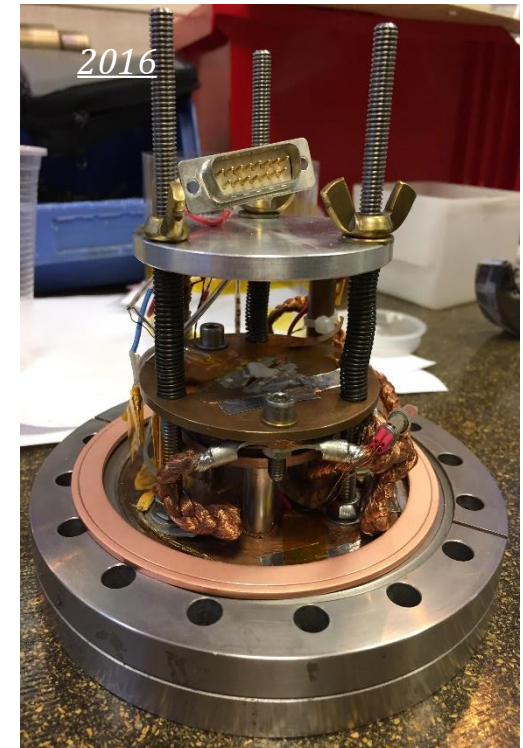
H_{c1} Measurement, a Local Magnetometer



Schematic of local magnetometer

How this magnetometer works ?

- Works have been beginning in 2010



Experimental setup

How this magnetometer works ?

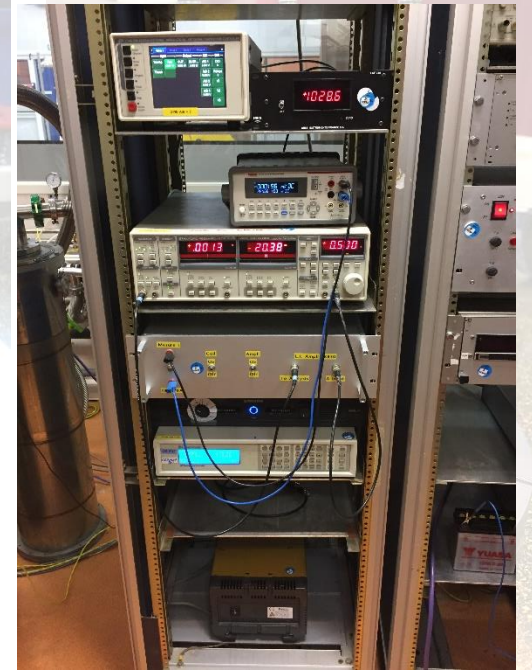
- Works have been beginning in 2010



Insert



Cryostat

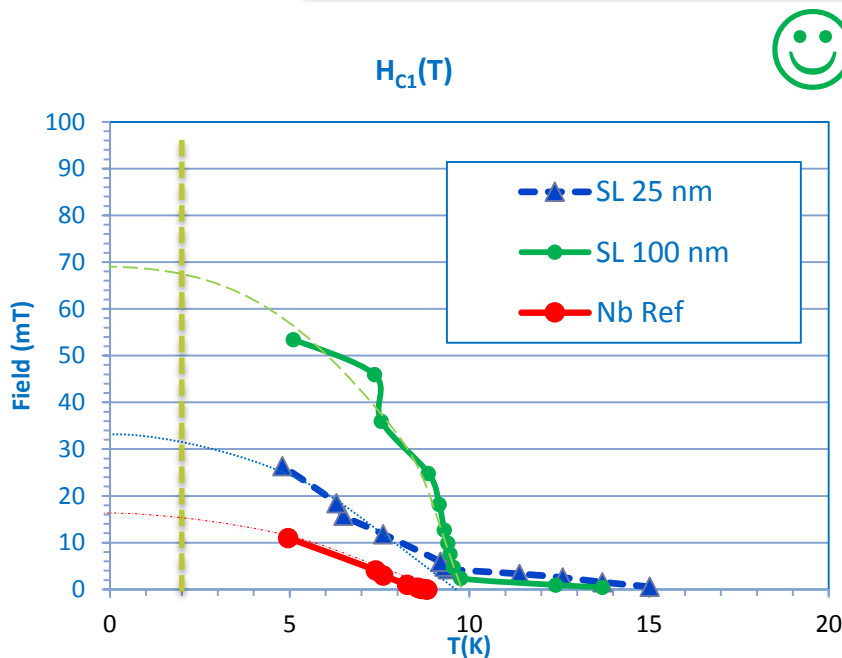


Measurement devices

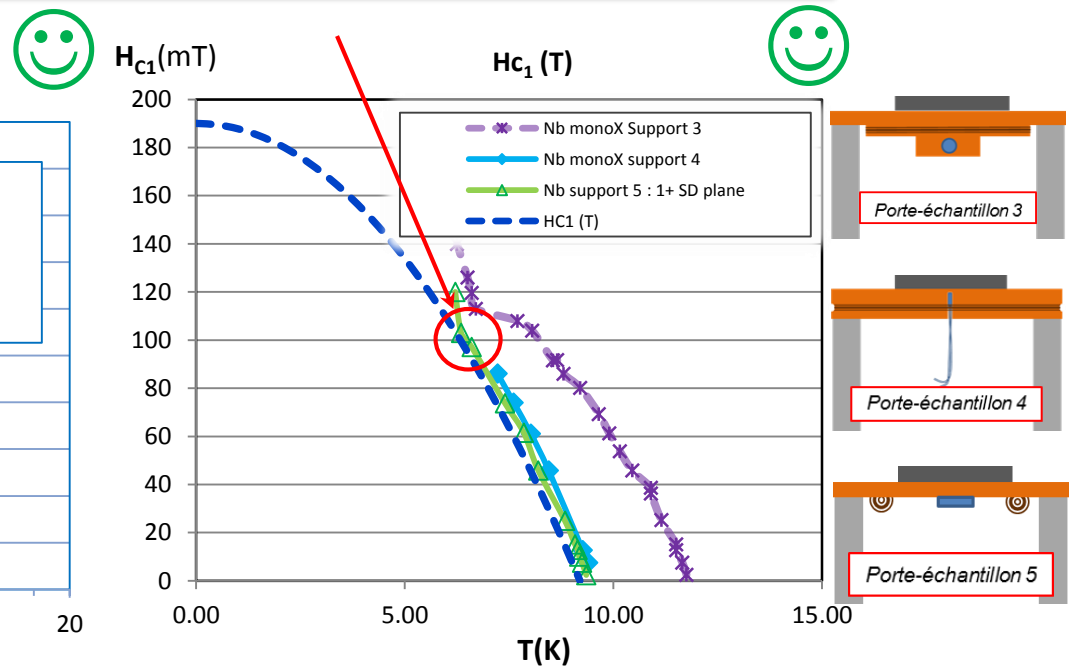
Behind every success, a lot of failures

- Many efforts were achieved to overcome some difficulties
- End of 2016, first successful measurement

Finally, a measurement done correctly until $\sim 100\text{mT}$



First acceptable results



Calibration with a monocrystalline Nb

Behind every success, a lot of failures

- Many efforts were achieved to overcome some difficulties

Problems !

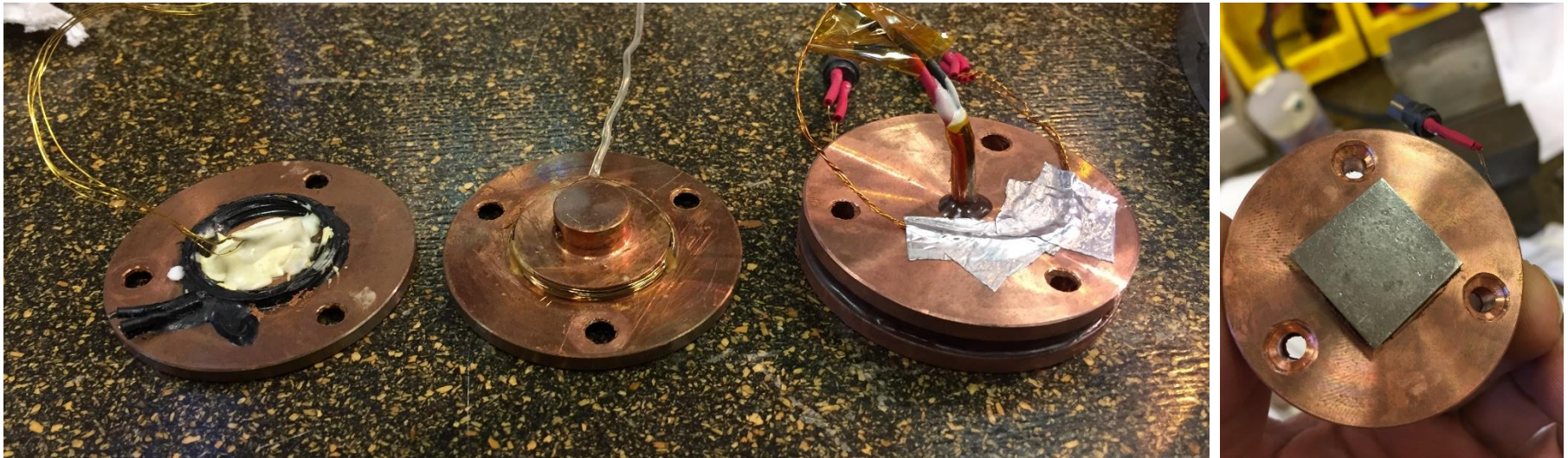
Thermal stabilizations

Calibration (important shift)

Modifications

Add some copper braids

The sample holder

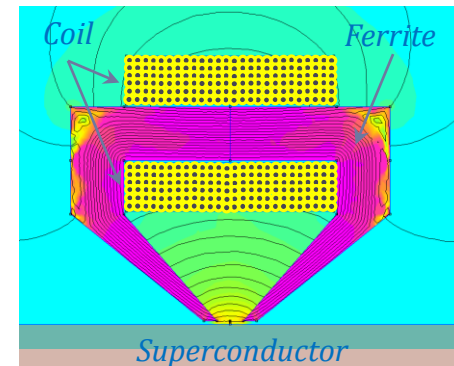
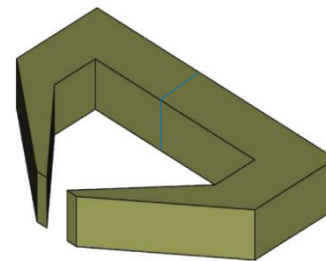


Conclusion

- ❑ A local magnetometer has proven to be effective at measuring vortex penetration in conditions close to cavities operating condition.
- ❑ We have shown a very promising behavior of NbN layers
- ❑ S-I-S multilayers provide best protection of cavities against local penetration of vortices
- ❑ Overcome Nb monopoly by higher H_{c1} superconductors multilayers is possible
- ❑ Sample gives results close to theory : optimization can be done theoretically
- ❑ Deposition methods inside cavities needs to be developed

Perspectives

- ❑ Enhancement of the maximum magnetic field applied on the sample, we hope to reach > 250 mT by:
 - Replacement the coil by a ferrite core inductor
 - Novel thermal design of the experimental setup
- ❑ Study other superconductors multilayers at higher fields.



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 - Second level
 - Third level
 - Fourth level
 - » Fifth level